# PDTC114Y series

NPN resistor-equipped transistors; R1 = 10 k $\Omega$ , R2 = 47 k $\Omega$ 

Rev. 7 — 18 November 2011

**Product data sheet** 

### 1. Product profile

### 1.1 General description

NPN Resistor-Equipped Transistor (RET) family in Surface-Mounted Device (SMD) plastic packages.

Table 1. Product overview

Type number	Package			PNP	Package	
	Nexperia	JEITA	JEDEC	complement	configuration	
PDTC114YE	SOT416	SC-75	-	PDTA114YE	ultra small	
PDTC114YM	SOT883	SC-101	-	PDTA114YM	leadless ultra small	
PDTC114YT	SOT23	-	TO-236AB	PDTA114YT	small	
PDTC114YU	SOT323	SC-70	-	PDTA114YU	very small	

#### 1.2 Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

### 1.3 Applications

- Digital applications in automotive and industrial segments
- Control of IC inputs

- Cost-saving alternative for BC847/857 series in digital applications
- Switching loads

#### 1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	50	V
Io	output current		-	-	100	mA
R1	bias resistor 1 (input)		7	10	13	kΩ
R2/R1	bias resistor ratio		3.7	4.7	5.7	



## 2. Pinning information

Table 3. **Pinning** Simplified outline **Graphic symbol** Pin Description SOT23; SOT323; SOT416 1 input (base) 3 2 GND (emitter) 3 output (collector) 2 006aaa144 sym007 **SOT883** 1 input (base) 2 GND (emitter) output (collector) Transparent

## 3. Ordering information

Table 4. Ordering information

Type number	Package	Package							
	Name	Description	Version						
PDTC114YE	SC-75	plastic surface-mounted package; 3 leads	SOT416						
PDTC114YM	SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 $\times$ 0.6 $\times$ 0.5 mm	SOT883						
PDTC114YT	-	plastic surface-mounted package; 3 leads	SOT23						
PDTC114YU	SC-70	plastic surface-mounted package; 3 leads	SOT323						

## 4. Marking

Table 5. Marking codes

Type number	Marking code <sup>[1]</sup>
PDTC114YE	33
PDTC114YM	DU
PDTC114YT	*27
PDTC114YU	*30

[1] \* = placeholder for manufacturing site code

## 5. Limiting values

Table 6. Limiting values

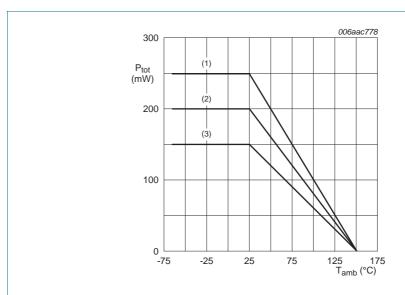
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter	-	50	V
$V_{CEO}$	collector-emitter voltage	open base	-	50	V
$V_{EBO}$	emitter-base voltage	open collector	-	6	V
VI	input voltage				
	positive		-	+40	V
	negative		-	-6	V
I <sub>O</sub>	output current		-	100	mA
I <sub>CM</sub>	peak collector current	$single \ pulse; \\ t_p \leq 1 \ ms$	-	100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$			
	PDTC114YE (SOT416)		[1][2]	150	mW
	PDTC114YM (SOT883)		[2][3]	250	mW
	PDTC114YT (SOT23)		[1] -	250	mW
	PDTC114YU (SOT323)		[1] -	200	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

<sup>[2]</sup> Reflow soldering is the only recommended soldering method.

<sup>[3]</sup> Device mounted on an FR4 PCB with 70  $\mu m$  copper strip line, standard footprint.



- (1) SOT23; FR4 PCB, standard footprint SOT883; FR4 PCB with 70  $\mu m$  copper strip line, standard footprint
- (2) SOT323; FR4 PCB, standard footprint
- (3) SOT416; FR4 PCB, standard footprint

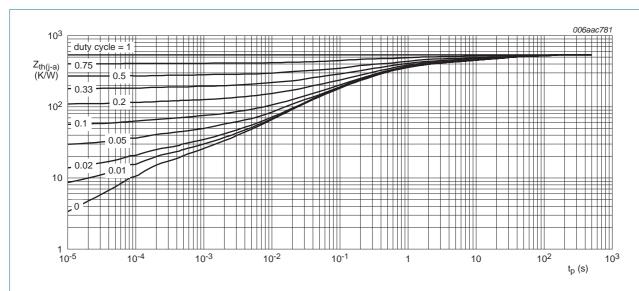
Fig 1. Power derating curves

### 6. Thermal characteristics

Table 7. Thermal characteristics

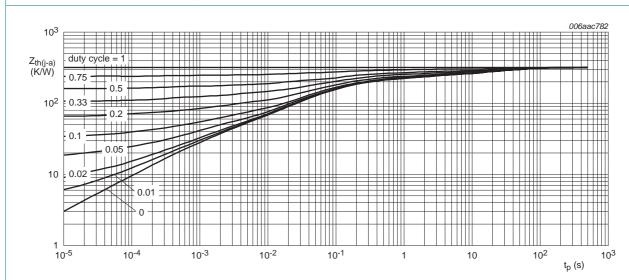
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air				
	PDTC114YE (SOT416)		[1][2]	-	830	K/W
	PDTC114YM (SOT883)		[2][3]	-	500	K/W
	PDTC114YT (SOT23)		<u>[1]</u> -	-	500	K/W
	PDTC114YU (SOT323)		<u>[1]</u> -	-	625	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Reflow soldering is the only recommended soldering method.
- [3] Device mounted on an FR4 PCB with 70  $\mu m$  copper strip line, standard footprint.



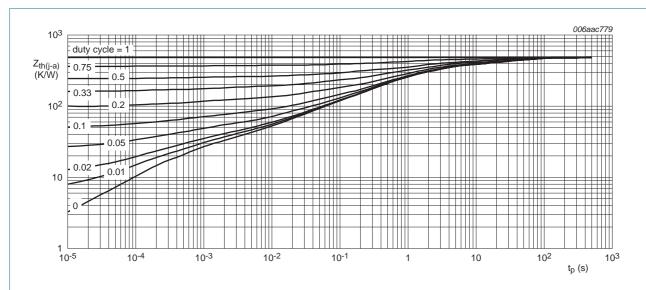
FR4 PCB, standard footprint

Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTC114YE (SOT416); typical values



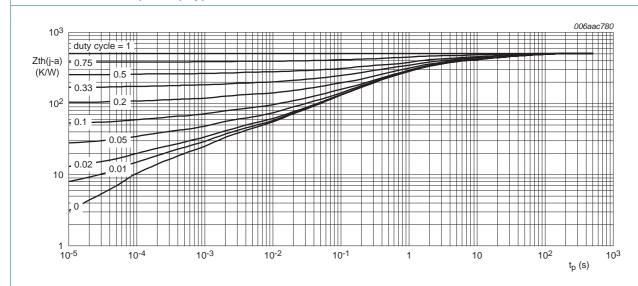
FR4 PCB, 70 µm copper strip line

Fig 3. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTC114YM (SOT883); typical values



FR4 PCB, standard footprint

Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTC114YT (SOT23); typical values



FR4 PCB, standard footprint

Fig 5. Transient thermal impedance from junction to ambient as a function of pulse duration for PDTC114YU (SOT323); typical values

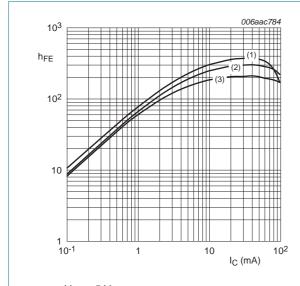
### 7. Characteristics

Table 8. Characteristics

T<sub>amb</sub> = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_E = 0 \text{ A}$		-	-	100	nA
I <sub>CEO</sub>	collector-emitter	$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}$		-	-	1	μΑ
cut-off current	cut-off current	$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A};$ $T_{j} = 150 ^{\circ}\text{C}$		-	-	5	μА
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}$		-	-	150	μА
h <sub>FE</sub>	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 5 \text{ mA}$		100	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = 5 \text{ mA}; I_B = 0.25 \text{ mA}$		-	-	100	mV
$V_{I(off)}$	off-state input voltage	$V_{CE} = 5 \text{ V}; I_{C} = 100 \mu\text{A}$		-	0.7	0.5	V
$V_{I(on)}$	on-state input voltage	$V_{CE} = 0.3 \text{ V}; I_{C} = 1 \text{ mA}$		1.4	8.0	-	V
R1	bias resistor 1 (input)			7	10	13	$k\Omega$
R2/R1	bias resistor ratio			3.7	4.7	5.7	
C <sub>c</sub>	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz		-	-	2.5	pF
f <sub>T</sub>	transition frequency	$V_{CE} = 5 \text{ V; } I_{C} = 10 \text{ mA;}$ f = 100 MHz	<u>[1]</u>	-	230	-	MHz

[1] Characteristics of built-in transistor



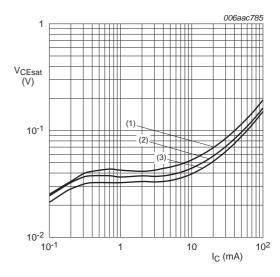


<sup>(1)</sup>  $T_{amb} = 100 \, ^{\circ}C$ 

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3)  $T_{amb} = -40 \, ^{\circ}C$ 

Fig 6. DC current gain as a function of collector current; typical values



 $I_{\rm C}/I_{\rm B} = 20$ 

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

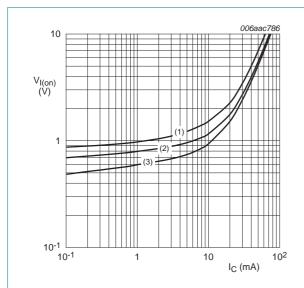
(3) 
$$T_{amb} = -40 \, ^{\circ}C$$

Fig 7. Collector-emitter saturation voltage as a function of collector current; typical values

PDTC114Y\_SER

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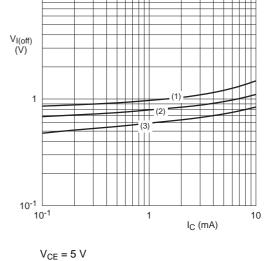
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 $V_{CE} = 0.3 \text{ V}$ 

- (1)  $T_{amb} = -40 \, ^{\circ}C$
- (2)  $T_{amb} = 25 \, ^{\circ}C$
- (3)  $T_{amb} = 100 \, ^{\circ}C$

Fig 8. On-state input voltage as a function of collector current; typical values



- (1)  $T_{amb} = -40 \, ^{\circ}C$

10

- (2)  $T_{amb} = 25 \, ^{\circ}C$
- (3)  $T_{amb} = 100 \, ^{\circ}C$

Fig 9. Off-state input voltage as a function of collector current; typical values

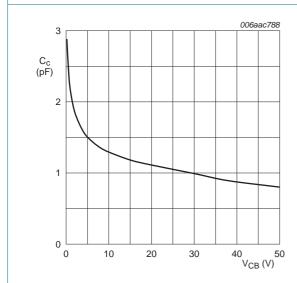
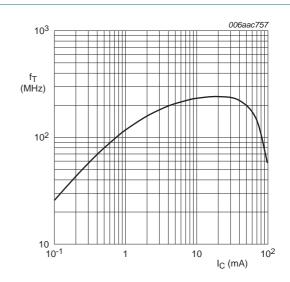


Fig 10. Collector capacitance as a function of collector-base voltage; typical values

 $f = 1 \text{ MHz}; T_{amb} = 25 \,^{\circ}\text{C}$ 



 $V_{CE}$  = 5 V;  $T_{amb}$  = 25 °C

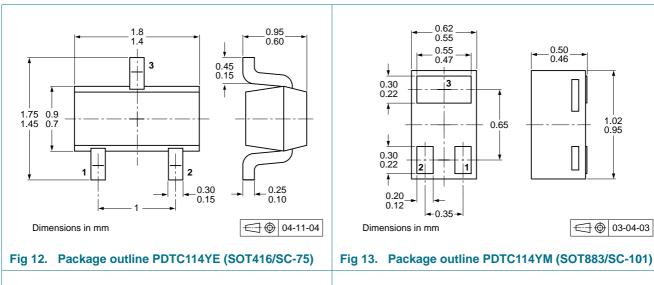
Fig 11. Transition frequency as a function of collector current; typical values of built-in transistor

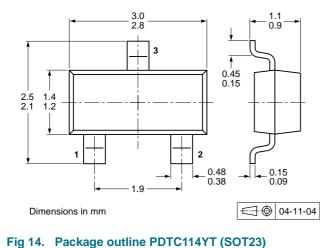
### **Test information**

### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

### Package outline





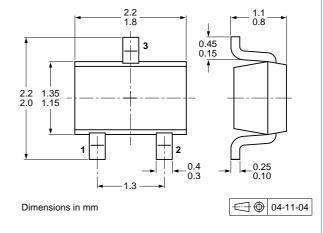


Fig 15. Package outline PDTC114YU (SOT323/SC-70)

NPN resistor-equipped transistors; R1 = 10 kΩ, R2 = 47 kΩ

## 10. Packing information

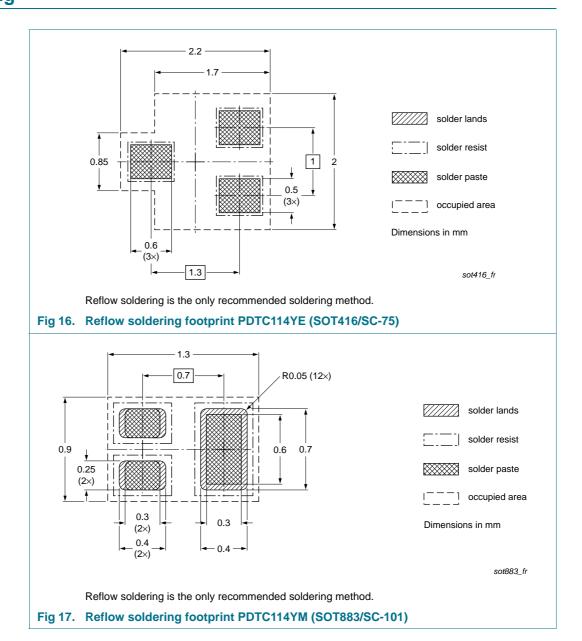
Table 9. Packing methods

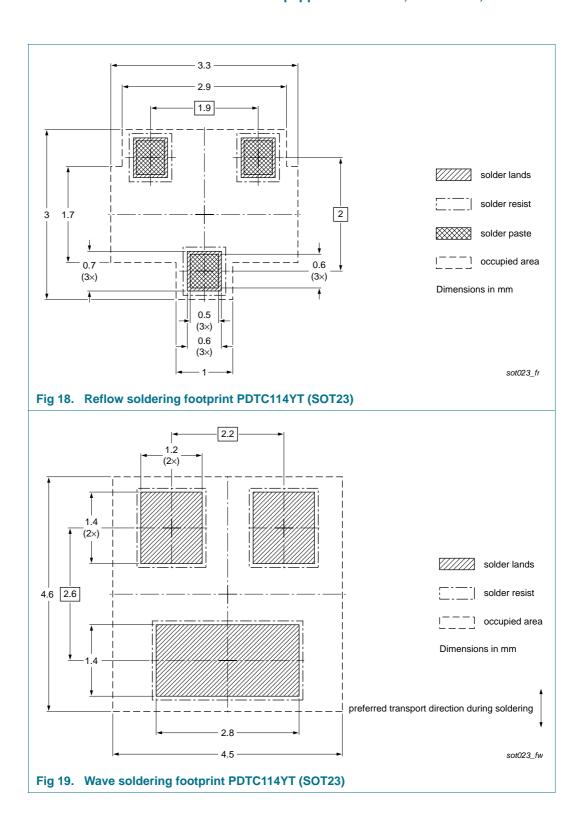
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

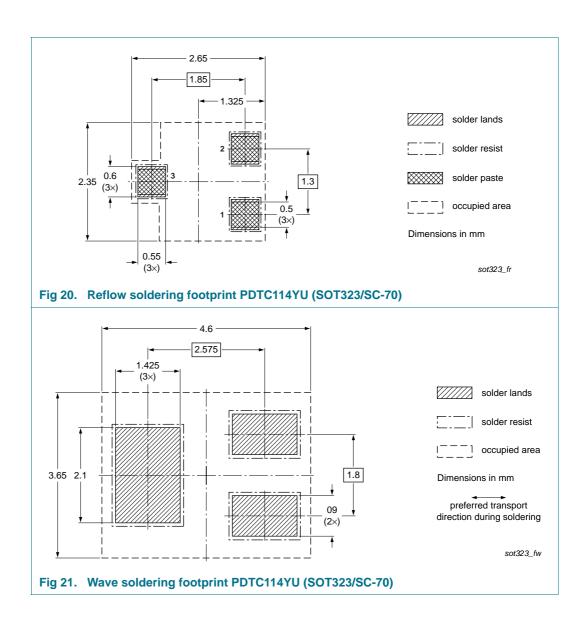
Type number Package		Description	Packing	Packing quantity		
			3000	5000	10000	
PDTC114YE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135	
PDTC114YM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315	
PDTC114YT	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235	
PDTC114YU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135	

<sup>[1]</sup> For further information and the availability of packing methods, see  $\underline{\text{Section 14}}$ .

### 11. Soldering







NPN resistor-equipped transistors; R1 = 10 kΩ, R2 = 47 kΩ

## 12. Revision history

### Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
PDTC114Y_SER v.7	20111118	Product data sheet	-	PDTC114Y_SERIES v.6		
Modifications:		this document has been rec NXP Semiconductors.	lesigned to comply wi	th the new identity		
	<ul> <li>Legal texts have</li> </ul>	ave been adapted to the new	company name where	re appropriate.		
	<ul> <li>Type number</li> </ul>	s PDTC114YEF, PDTC114Y	K and PDTC114YS re	moved.		
	<ul> <li>Section 1 "President 1"</li> </ul>	oduct profile": updated				
	<ul> <li>Section 3 "Or</li> </ul>	dering information": added				
	<ul> <li>Section 4 "Ma</li> </ul>	arking": updated				
	<ul> <li>Figure 1 to 11</li> </ul>	: added				
	<ul> <li>Section 5 "Lir</li> </ul>	niting values": updated				
	Section 6 "Thermal characteristics": updated					
	<ul> <li><u>Table 8 "Characteristics"</u>: V<sub>i(on)</sub> redefined to V<sub>I(on)</sub> on-state input voltage, V<sub>i(off)</sub> redefined to V<sub>I(off)</sub> off-state input voltage, I<sub>CEO</sub> updated, f<sub>T</sub> added</li> </ul>					
	Section 8 "Tell	st information": added				
	Section 9 "Package outline": superseded by minimized package outline drawings					
	<ul> <li>Section 10 "P</li> </ul>	acking information": added				
	<ul> <li>Section 11 "S</li> </ul>	oldering": added				
	<ul> <li>Section 13 "L</li> </ul>	egal information": updated				
PDTC114Y_SERIES v.6	20040817	Product data sheet	-	PDTC114Y_SERIES v.5		
PDTC114Y_SERIES v.5	20040910	Product specification	-	PDTC114Y_SERIES v.4		
PDTC114Y_SERIES v.4	20030414	Product specification	-	-		

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#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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# **PDTC114Y series**

NPN resistor-equipped transistors; R1 = 10 kΩ, R2 = 47 kΩ

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SMUN5114DW1T1G SMUN2111T1G NSVDTC144EM3T5G DTC124ECA-TP DTC123TM3T5G DTA114ECA-TP DTA113EM3T5G

DCX115EK-7-F DTC113EM3T5G NSVMUN5135DW1T1G NSVMUN2237T1G